

	<h2 style="color: red;">RFD14N05SM9A</h2>	
	Hersteller-Teilenummer:	RFD14N05SM9A
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET N-CH 50V 14A DPAK
Image may be representation. See specs for product details.	Datenblätter:	1.RFD14N05SM9A.pdf 2.RFD14N05SM9A.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 76996 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	RFD14N05SM9A
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 50V 14A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	76996 pcs Stock
Hersteller Standard Vorlaufzeit	6 Weeks
detaillierte Beschreibung	N-Channel 50V 14A (Tc) 48W (Tc) Surface Mount TO-
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252AA
Verlustleistung (max)	48W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	50V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	14A (Tc)
Rds On (Max) @ Id, Vgs	100 mOhm @ 14A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 20V
Eingabekapazität (Ciss) (Max) @ Vds	570pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Cut Tape (CT)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	RFD14N05SM9ACT

RFD14N05SM9A ist neu im Original, Suche RFD14N05SM9A Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RFD14N05SM9A AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage RFD14N05SM9A: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>RFD14N06 I RFD14N06 I</p>	 <p>RFD14N05SM96 Original TO-252</p>	 <p>RFD14N05LSM9A Fairchild/ON Semiconductor MOSFET N-CH 50V 14A TO-252AA</p>	 <p>RFD14N05SM Fairchild/ON Semiconductor MOSFET N-CH 50V 14A TO-252AA</p>
 <p>RFD14N05SM9 Original RFD14N05SM9 Original</p>	 <p>RFD14N05SM9A Fairchild/ON Semiconductor MOSFET N-CH 50V 14A DPAK</p>	 <p>RFD14N06LSM I I TO-252A</p>	 <p>RFD14N05SM AMI Semiconductor / ON Semiconductor MOSFET N-CH 50V 14A TO-252AA</p>

heiße Teile

Mehr

⊗ RFD10N05SM96	↔ RFD10P03L-251	⇒ RFD10P03LSM	D RFD10P03LSM	↗ RFD10P05
⊣ RFD12N06LE	⊗ RFD12N06LESM	D RFD12N06REL	⇒ RFD12N06RLE	↗ RFD12N06RLE
⊗ RFD12N06RLESM	⊣ RFD12N06RLESM9A	⊗ RFD12N06RLESM9A	↔ RFD14N05	↗ RFD14N05
D RFD14N05L	⊗ RFD14N05L	⊣ RFD14N05LSM	⊗ RFD14N05LSM	↗ RFD14N05LSM9A
⇒ RFD14N05LSM9A	↔ RFD14N05SM	⊗ RFD14N05SM	⊣ RFD14N05SM9	↗ RFD14N05SM9A
↔ RFD15N05	⇒ RFD15N05LSM	D RFD15N06LE	⊗ RFD15N06LESM	⊣ RFD15P05
⊗ RFD15P05	D RFD15P05SM	⇒ RFD15P05SM	↔ RFD15P05SM9A	↗ RFD15P06
⊣ RFD15P06LSM	⊗ RFD15P06SM	↔ RFD15P06SM9AS2463	⇒ RFD16N02	↗ RFD16N02L
⊗ RFD16N02LSM	⊣ RFD16N02LSM9A	⊗ RFD16N03L	D RFD16N03LSM	↗ RFD16N03LSM9A
↔ RFD16N05	⊗ RFD16N05	⊣ RFD16N05L	⊗ RFD16N05LSM	↗ RFD16N05LSM

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